

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL PLANAR TYPE

HN3C02F

TV TUNER, UHF OSCILLATOR APPLICATION.
TV TUNER, UHF CONVERTER APPLICATION.

- Including Two Devices in SM6 (Super Mini Type with 6Leads)
- High Transition Frequency : $f_T=2400\text{MHz}$ (Typ.)

MAXIMUM RATINGS (Ta = 25°C) (Q1, Q2)

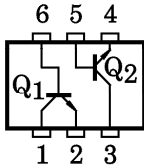
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	15	V
Emitter-Base Voltage	V_{EBO}	3	V
Collector Current	I_C	50	mA
Base Current	I_B	25	mA
Collector Power Dissipation	P_C^*	300	mW
Junction Temperature	T_j	125	°C
Storage Temperature Range	T_{stg}	-55~125	°C

* Total

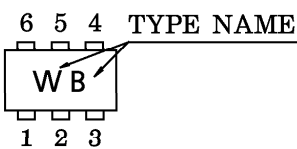
ELECTRICAL CHARACTERISTICS (Ta = 25°C) (Q1, Q2)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=30\text{V}, I_E=0$	—	—	0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=2\text{V}, I_C=0$	—	—	1.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1\text{mA}, I_B=0$	15	—	—	V
DC Current Gain	h_{FE}	$V_{CE}=10\text{V}, I_E=5\text{mA}$	40	—	200	—
Transition Frequency	f_T	$V_{CE}=10\text{V}, I_C=2\text{mA}, f=800\text{MHz}$	1500	2400	—	MHz
Reverse Transfer Capacitance Q1	$C_{re(1)}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$	—	0.53	0.85	pF
Reverse Transfer Capacitance Q2	$C_{re(2)}$	$V_{CB}=10\text{V}, I_E=0, f=1\text{MHz}$	—	0.48	0.80	pF
Collector-Base Time Constant Q1	$C_c\text{'rbb' (1)}$	$V_{CB}=10\text{V}, I_C=2\text{mA}, f=30\text{MHz}$	—	15.0	22.0	ps
Collector-Base Time Constant Q2	$C_c\text{'rbb' (2)}$	$V_{CB}=10\text{V}, I_C=2\text{mA}, f=30\text{MHz}$	—	14.5	21.5	ps

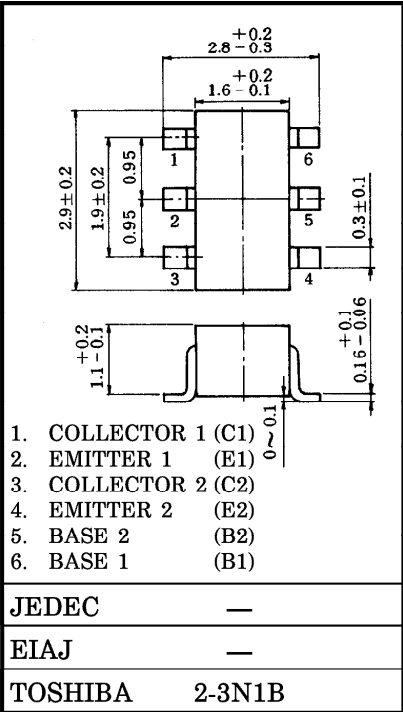
PIN ASSIGNMENT (TOP VIEW)



MARKING



Unit in mm



961001EAA2

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